

TECHNICAL DATA
DATA SHEET 285, REV -

TRANSIENT VOLTAGE SUPPRESSOR DIODE
(500 Watt)

DESCRIPTION: 5.2 VOLT, 175 MILLIAMP, AXIAL LEAD TRANSIENT VOLTAGE SUPPRESSOR DIODE.

MAX. RATINGS / ELECTRICAL CHARACTERISTICS All ratings are at $T_A = 25^\circ\text{C}$ unless otherwise specified.

RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Breakdown Voltage @ I_{BR}		6.12 6.46	-	-	Vdc
Test Current (I_{BR})		-	-	175	mAmps dc
Working Peak Reverse Voltage (V_{RWM})		-	-	5.2	Vdc
Maximum Reverse Current (I_{R1})	$T_A = 25^\circ\text{C}$ $T_A = 125^\circ\text{C}$	-	-	100 500	$\mu\text{Amps dc}$
Maximum Clamp Voltage $V_{C(max)}$	@ $I_P, t_p = 1\text{ms}$	-	-	11.0 10.5	Volts (pk)
Maximum Peak Pulse Current (I_P)		-	-	45.4 47.6	Amps (pk)
Maximum Temperature Coefficient ($V_{(BR)}$)		-	-	.05	%/ $^\circ\text{C}$
Maximum Reverse Current (I_R)	@ $T_A = 150^\circ\text{C}$	-	-	4000	$\mu\text{Amps dc}$
Operating and Storage Temp. (T_{op} & T_{stg})		-55	-	+175	$^\circ\text{C}$

Notes:

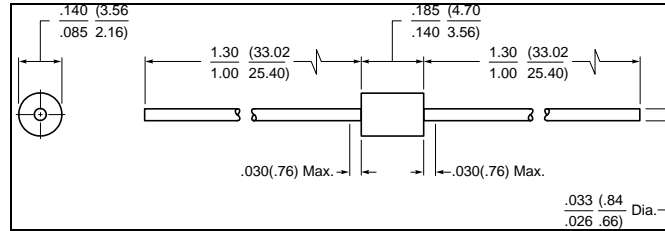
$P_R = 2\text{W}$ for 500W peak pulse power devices at $T_A = +25^\circ\text{C}$.

$P_R = 3\text{W}$ (for 500W peak pulse power devices at $T_L = +75^\circ\text{C}$ for $L = 0.375$ inch (9.53mm)).

$P_{PR} = 500\text{W}$

$-55^\circ\text{C} \leq T_{op} \leq +175^\circ\text{C}$, $-55^\circ\text{C} \leq T_{stg} \leq +175^\circ\text{C}$ (ambient temperatures).

MECHANICAL DIMENSIONS In Inches / (mm), min./max.



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